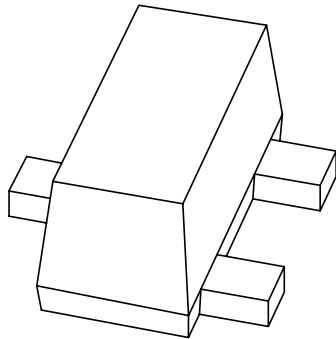


DATA SHEET



**1PS89SB14; 1PS89SB15;
1PS89SB16**
Schottky barrier double diodes

Product specification
Supersedes data of 1998 Nov 10

2003 Apr 28

Schottky barrier double diodes

1PS89SB14; 1PS89SB15; 1PS89SB16

FEATURES

- Power dissipation comparable to SOT23
- Low forward voltage
- Guard ring protected
- Ultra small SMD package.

APPLICATIONS

- Ultra high speed switching
- Voltage clamping
- Protection circuits
- Blocking diodes.

DESCRIPTION

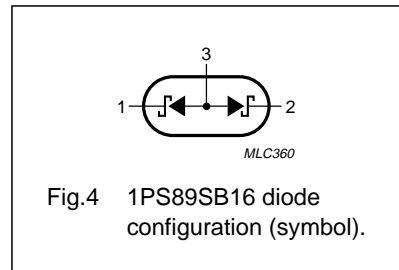
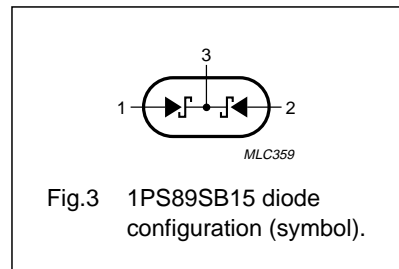
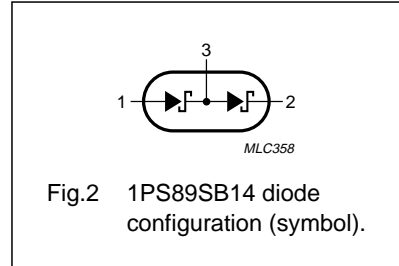
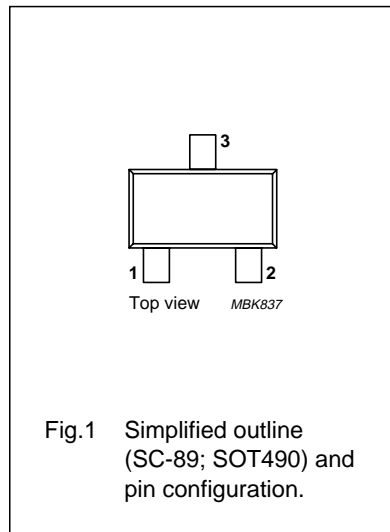
Planar Schottky barrier double diodes encapsulated in an ultra small plastic SMD SC-89 (SOT490) package.

MARKING

TYPE NUMBER	MARKING CODE
1PS89SB14	44
1PS89SB15	43
1PS89SB16	45

PINNING

PIN	1PS89SBxx		
	14	15	16
1	a ₁	a ₁	k ₁
2	k ₂	a ₂	k ₂
3	k ₁ , a ₂	k ₁ , k ₂	a ₁ , a ₂



Schottky barrier double diodes

1PS89SB14; 1PS89SB15;
1PS89SB16**LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode unless otherwise specified					
V_R	continuous reverse voltage		–	30	V
I_F	continuous forward current		–	200	mA
I_{FRM}	repetitive peak forward current	$t_p \leq 1 \text{ s}; \delta \leq 0.5$	–	300	mA
I_{FSM}	non-repetitive peak forward current	$t_p < 10 \text{ ms}$	–	600	mA
P_{tot}	total power dissipation (per package)	$T_{amb} \leq 25 \text{ }^\circ\text{C}$	–	200	mW
T_{stg}	storage temperature		–65	+150	$^\circ\text{C}$
T_j	junction temperature		–	125	$^\circ\text{C}$
T_{amb}	operating ambient temperature		–65	+125	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS $T_{amb} = 25 \text{ }^\circ\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
Per diode unless otherwise specified				
V_F	forward voltage	see Fig.5 $I_F = 0.1 \text{ mA}$ $I_F = 1 \text{ mA}$ $I_F = 10 \text{ mA}$ $I_F = 30 \text{ mA}$ $I_F = 100 \text{ mA}$	240 320 400 500 800	mV mV mV mV mV
I_R	reverse current	$V_R = 25 \text{ V}$; note 1; see Fig.6	2	μA
C_d	diode capacitance	$f = 1 \text{ MHz}$; $V_R = 1 \text{ V}$; see Fig.7	10	pF

Note

1. Pulse test: $t_p \leq 300 \text{ } \mu\text{s}$; $\delta \leq 0.02$.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th j-a}$	thermal resistance from junction to ambient	note 1	500	K/W

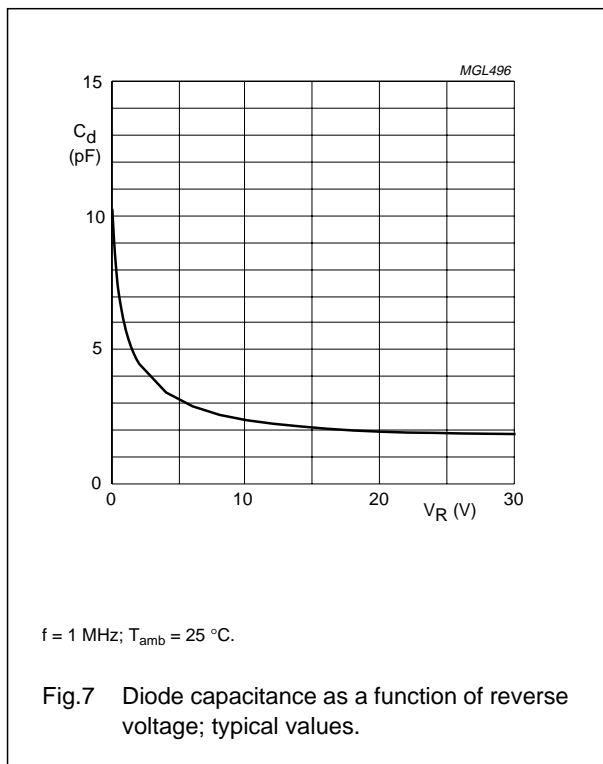
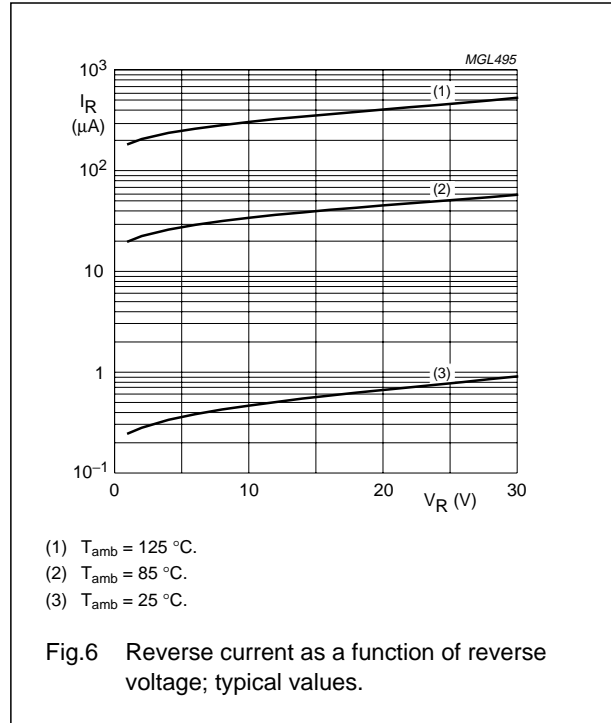
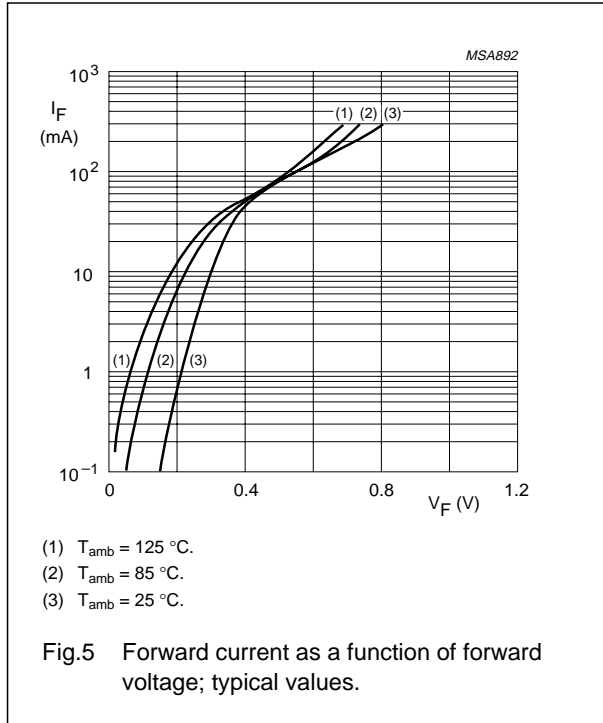
Note

1. Refer to SC-89 (SOT490) standard mounting conditions.

Schottky barrier double diodes

1PS89SB14; 1PS89SB15;
1PS89SB16

GRAPHICAL DATA



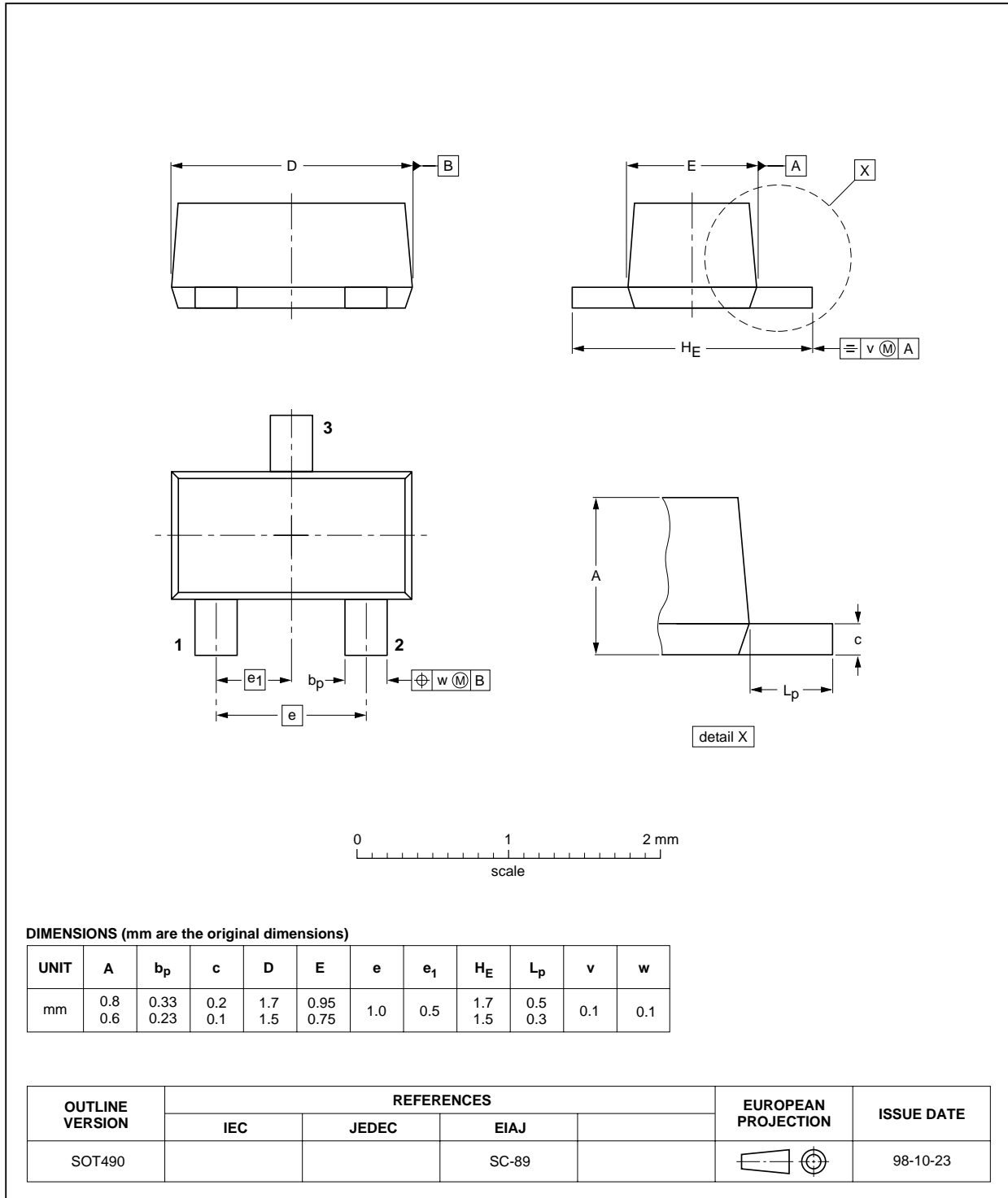
Schottky barrier double diodes

1PS89SB14; 1PS89SB15;
1PS89SB16

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT490



Schottky barrier double diodes

1PS89SB14; 1PS89SB15;
1PS89SB16

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

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2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.
3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device.

These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Schottky barrier double diodes

1PS89SB14; 1PS89SB15;
1PS89SB16

NOTES

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